

B L GALAXY ELECTRICAL

BYM26A(Z) --- BYM26E(Z)

SUPER FAST RECTIFIER

VOLTAGE RANGE: 200 --- 1000 V
CURRENT: 2.3 A

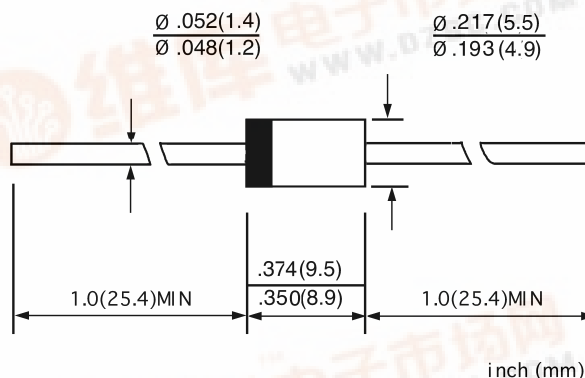
FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

DO - 27



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		BYM26A	BYM26B	BYM26C	BYM26D	BYM26E	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @T _A =75°C	I _{F(AV)}	2.3					A
Peak forward surge current 10 ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	45.0					A
Maximum instantaneous forward voltage @ 2.0A	V _F	2.65					V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 150.0					μA
Maximum reverse recovery time (Note1)	t _{rr}	30			75		ns
Typical junction capacitance (Note2)	C _J	85			75		pF
Typical thermal resistance (Note3)	R _{θJA}	75					°C/W
Operating junction temperature range	T _J	- 55 ----- + 150					°C
Storage temperature range	T _{STG}	- 55 ----- + 150					°C

NOTE: 1. Measured with $I_F=0.5A$, $I_R=1A$, $t_{rr}=0.25A$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 -- FORWARD DERATING CURVE

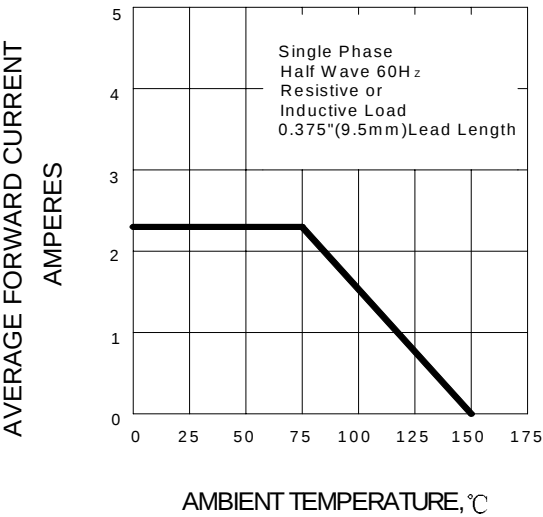


FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

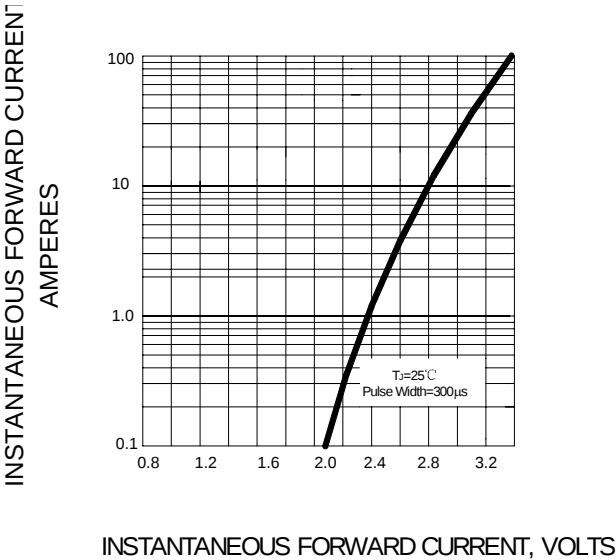


FIG.3 -- PEAK FORWARD SURGE CURRENT

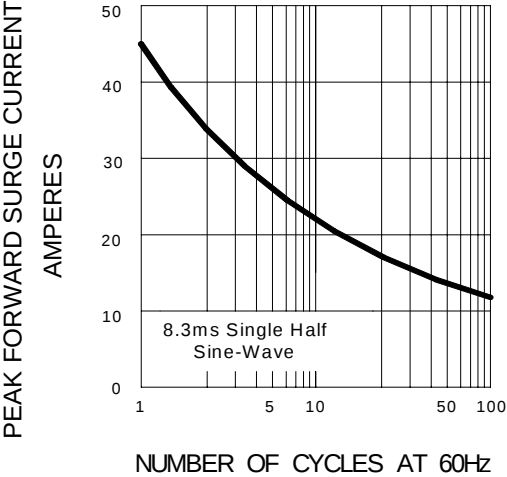


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

